

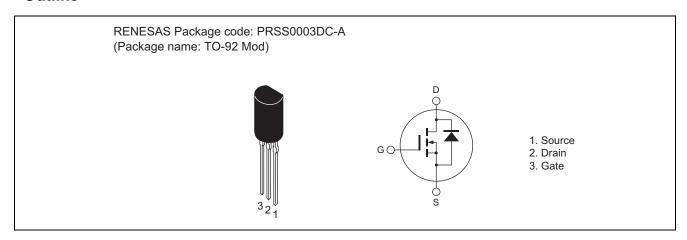
# RJK6011DJE

600V - 0.1A - MOS FET High Speed Power Switching R07DS1153EJ0400 (Previous: REJ03G1577-0300) Rev.4.00 Jan 28, 2014

### **Features**

- Low on-resistance  $R_{DS(on)} = 35~\Omega~typ.~(at~I_D=0.05~A,~V_{GS}=10~V,~Ta=25^{\circ}C)$
- Low drive current
- High density mounting

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	$V_{DSS}$	600	V
Gate to source voltage	$V_{GSS}$	±30	V
Drain current	I <sub>D</sub>	0.1	Α
Drain peak current	I <sub>D (pulse)</sub> Note1	0.4	Α
Body-drain diode reverse drain current	I <sub>DR</sub>	0.1	Α
Body-drain diode reverse drain peak current	I <sub>DR (pulse)</sub> Note1	0.4	Α
Channel dissipation	Pch	0.9	W
Channel to ambient thermal impedance	$ heta_{ch-a}$	139	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1.  $PW \le 10 \mu s$ , duty cycle  $\le 1\%$ 

## **Electrical Characteristics**

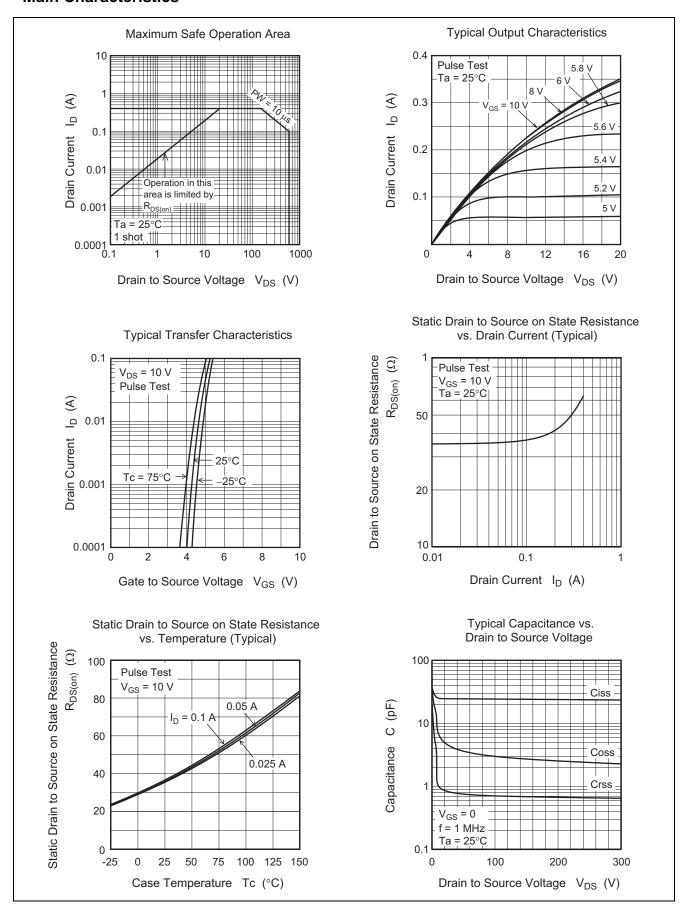
 $(Ta = 25^{\circ}C)$ 

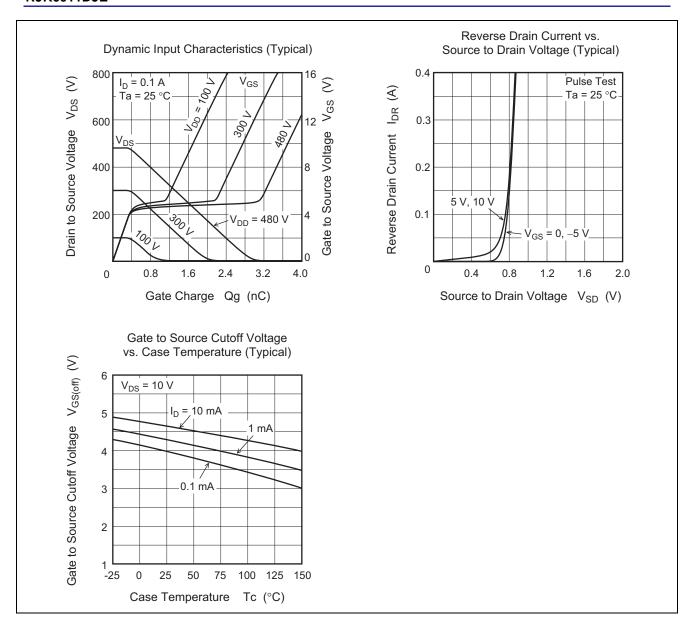
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	600	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	1	μΑ	$V_{DS} = 600 \text{ V}, V_{GS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	_	±0.1	μΑ	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	3	_	5	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Static drain to source on state	R <sub>DS(on)</sub>	_	35	52	Ω	$I_D = 0.05 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note2}}$
resistance						
Input capacitance	Ciss	_	25	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	4.7	_	pF	V <sub>GS</sub> = 0 f = 1 MHz
Reverse transfer capacitance	Crss	_	0.9	_	pF	
Turn-on delay time	t <sub>d(on)</sub>	_	33	_	ns	$I_D = 0.05 A$
Rise time	t <sub>r</sub>	_	16	_	ns	$V_{GS} = 10 \text{ V}$ $R_L = 6000 \Omega$ $Rg = 10 \Omega$
Turn-off delay time	t <sub>d(off)</sub>	_	54	_	ns	
Fall time	t <sub>f</sub>	_	300	_	ns	
Total gate charge	Qg	_	3.7	_	nC	V <sub>DD</sub> = 480 V
Gate to source charge	Qgs	_	0.4	_	nC	V <sub>GS</sub> = 10 V
Gate to drain charge	Qgd	_	2.7	_	nC	$I_D = 0.1 A$
Body-drain diode forward voltage	$V_{DF}$	_	0.80	1.35	V	$I_F = 0.1 \text{ A}, V_{GS} = 0^{\text{Note2}}$

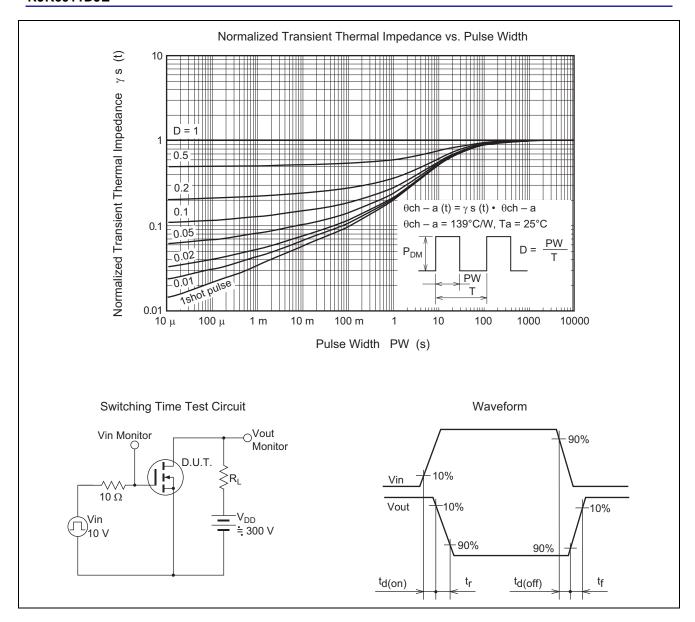
Notes: 2. Pulse test

- 3. Since this device is equipped with high voltage FET chip ( $V_{DSS} \ge 600 \text{ V}$ ), high voltage may be supplied. Therefore, please be sure to confirm about Electric discharge between Drain terminal and other terminal.
- 4. This device is sensitive to electrostatic discharge. It is recommended to adopt appropriate cautions when handling this product.

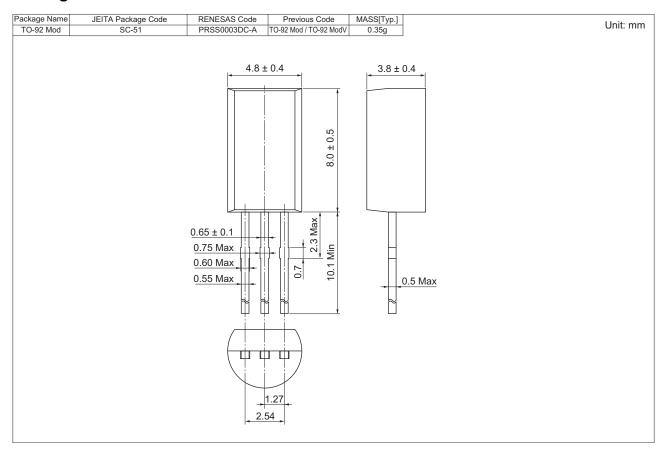
### **Main Characteristics**







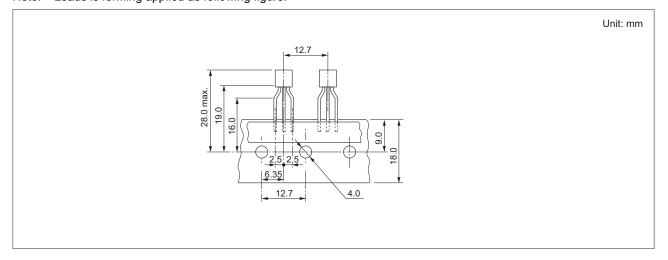
# **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
RJK6011DJE-00#Z0	2500 pcs	Hold Box, Radial Taping

Note: Leads is forming applied as following figure.



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